

NTLJD3119CTAG

Data Sheet

Power MOSFET 20 V/-20 V, 4.6 A/-4.1 A, uCool Complementary, 2x2 mm, WDFN Package, MOSFET COMP 2X2 20V 3.8A 100mOhm

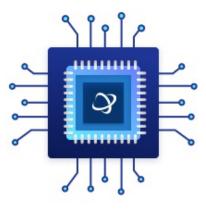
Manufacturers ON Semiconductor, LLC

Package/Case 506AN

Product Type Transistors

RoHS Rohs

Lifecycle



Images are for reference only

ONSEMI

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General Description

Power MOSFET20 V/-20 V, 4.6 A/-4.1 A, Complementary, 2x2 mm, WDFN Package

Features Application

Complementary N-Channel and P-Channel MOSFET

Easy Circuit Layout, Circuit Design Flexibility

WDFN Package with Exposed Drain Pad for Excellent Thermal Conduction

Excellent Thermal Conduction

Leading Edge Trench Technology for Low On Resistance

1.8 V Gate Threshold Voltage

Low Profile (< 0.8 mm) for Easy Fit in Thin Environments

Related Products



NTR4003NT3G
ON Semiconductor, LLC
SOT-23



ON Semiconductor, LLC TO-252

NTD2955G



NTZD3155CT2G

ON Semiconductor, LLC
SOT-563-6



NTR5103NT1G
ON Semiconductor, LLC
SOT-23



NTHD4102PT1G
ON Semiconductor, LLC
ChipFET-8



NTS2101PT1G
ON Semiconductor, LLC
SOT-323



NTMFS4C10NT1G
ON Semiconductor, LLC
SO-8FL



NTH4L020N120SC1
ON Semiconductor, LLC
TO-247